

BLF041SURC/E12V HYPER RED

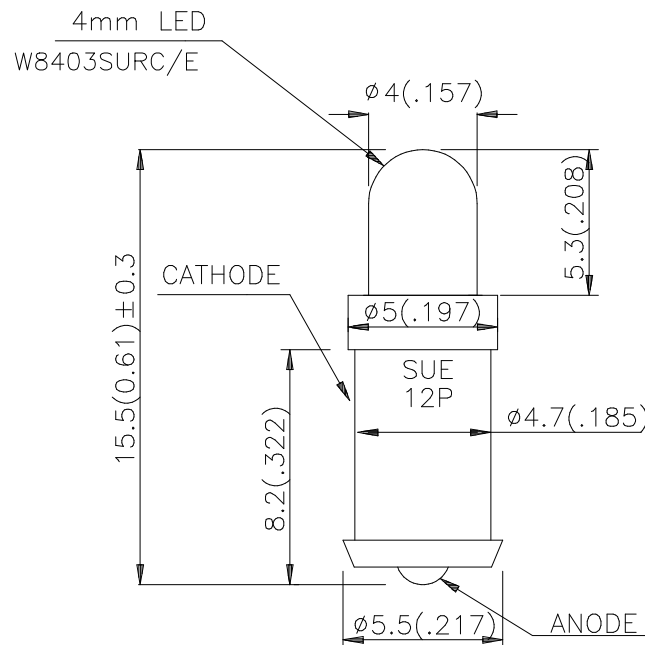
Features

- BUILT-IN CURRENT LIMITING RESISTOR FOR DIRECT APPLICATION OF DIFFERENT ACROSS CURRENT.
- LONG LIFE.
- LOW CURRENT, POWER SAVINGS.
- LOW MAINTENANCE.
- DIFFERENT COLOR AVAILABLE.
- SOLID STATE, HIGH VIBRATION RESISTANT.
- 12V INTERNAL RESISTOR.

Description

The Hyper Red source color devices are made with DH InGaAlP on GaAs substrate Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01)$ " unless otherwise noted.
3. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) V=12V		Viewing Angle
			Min.	Typ.	2θ1/2
BLF041SURC/E12V	HYPER RED (InGaAlP)	WATER CLEAR	480	1200	30°

Note:

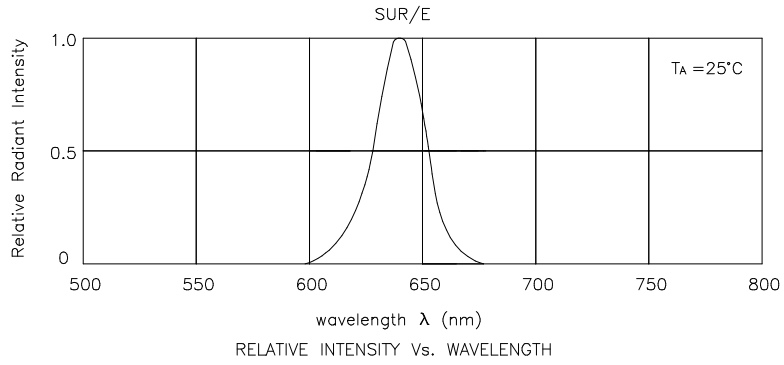
1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at T_A=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ _{peak}	Peak Wavelength	Hyper Red	640	-	nm	V _F =12V
λ _D	Wavelength at Dominate	Hyper Red	630	-	nm	V _F =12V
Δλ _{1/2}	Spectral Line Half-width	Hyper Red	25	-	nm	V _F =12V
C	Capacitance	Hyper Red	45	-	pF	V _F =0V;f=1MHz
I _F	Forward Current	Hyper Red	20	-	mA	V _F =12V
I _R	Reverse Current	Hyper Red	-	10	uA	V _R = 5V

Absolute Maximum Ratings at T_A=25°C

Parameter	Hyper Red	Units
Power dissipation	300	mW
Forward Voltage	14	V
Reverse Voltage	5	V
Operating Temperature	-40°C To +70°C	
Storage Temperature	-40°C To +85°C	



Hyper Red

BLF041SURC/E12V

